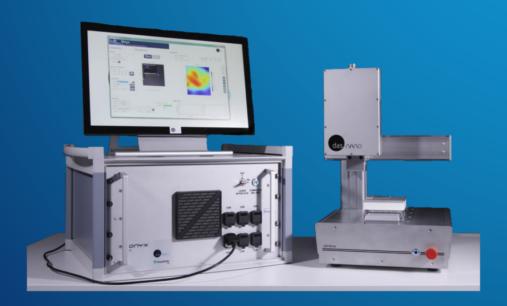


Onyx



Graphene and 2D materials characterization

Onyx

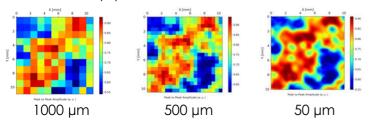
Ultra-fast graphene and 2D materials characterization

Onyx is the first system in the market designed to provide a full-area non-destructive characterization of Graphene, thin-films, and other 2D materials. Onyx covers the gap between the macro and the nanoscale tools, characterizing from 0,5 mm2 to large areas (m²), enhancing the industrialization of research materials.

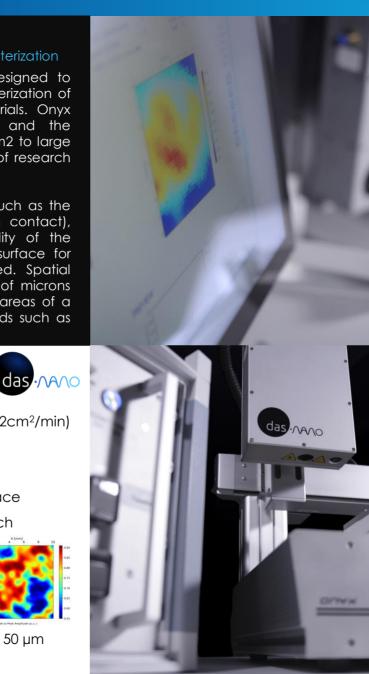
Compared to other large-area methods, such as the Four Probe method (destructive and with contact), Onyx is capable of measuring the quality of the sample, offering a complete map of its surface for each electrical property that is measured. Spatial resolution in the order of a few hundreds of microns enables the fast characterization of large areas of a sample as opposed to microscopic methods such as Raman, SEM, and TEM.

FEATURES

- ✓ Contactless measurement
- ✓ Ultra-fast full surface characterization (12cm²/min)
- ✓ High resolution. Up to 50 µm
- ✓ No sample preparation needed
- ✓ Powerful & friendly-use graphical interface
- ✓ Versatile equipment: industrial & research



www.das-nano.com/onyx



DNYX can measure...

- ✓ Sheet conductance/resistance
- ✓ DC sheet conductance/resistance
- ✓ Mobility

- ✓ Carrier density
- ✓ Scattering time
- √ Homogeneity

Of a wide variety of materials!

Graphene

- CVD monolayer
- CVD multi-layer
- Epitaxial
- Powder & Flakes
- Inks
- Doped
- Graphene Oxide
- Nanoplatelets



Other thin films

- PEDOT
- Indium Tin Oxide (ITO)
- Indium Gallium Zinc Oxide (IZGO)
- Gallium Nitride (GaN)
- Molybdenum disulphide (MoS 2)
- Ag nanowires
- Titanium nitride (TiN)
- Hexagonal Boron Nitride (hBN)

and many more!



NDT & Terahertz systems

www.das-nano.com

info@das-nano.com | +34 948 246 295

Polígono Industrial Talluntxe II, Calle M-10, 31192, Tajonar, Navarra, Spain